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Bib Data Sheet

CONFIRMATION NO. 6761

SERIAL NUMBER 09/856,212	FILING OR 371(c) DATE 05/18/2001 RULE	CLASS 117	GROUP ART UNIT 1722	ATTORNEY DOCKET NO. 82821
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APPLICANTS

Kozo Nakamura, Kanagawa, JAPAN;
 Toshiaki Saishoji, Kanagawa, JAPAN;
 Hirotaka Nakajima, Kanagawa, JAPAN;
 Shinya Sadohara, Kanagawa, JAPAN;
 Masashi Nishimura, Kanagawa, JAPAN;
 Toshiro Kotooka, Nagasaki, JAPAN;
 Yoshiyuki Shimanuki, Kanagawa, JAPAN;

**** CONTINUING DATA *******

This application is a 371 of PCT/JP99/06477 11/19/1999 M>

**** FOREIGN APPLICATIONS *******

JAPAN 10/330713 11/20/1998
 JAPAN 11/77166 03/23/1999 M>
 JAPAN 11/129957 05/11/1999

Foreign Priority claimed <input checked="" type="checkbox"/> yes <input type="checkbox"/> no	STATE OR COUNTRY JAPAN	SHEETS DRAWING 16	TOTAL CLAIMS 23	INDEPENDENT CLAIMS 15
35 USC 119 (a-d) conditions met <input checked="" type="checkbox"/> yes <input type="checkbox"/> no <input type="checkbox"/> Met after Allowance				
Verified and Acknowledged Examiner's Signature <i>M></i> Initials <i>M></i>				

ADDRESS
 24628

TITLE

Production method for silicon single crystal and production device for single crystal ingot, and heat treating method for silicon single crystal wafer

FILING FEE RECEIVED 1874	FEES: Authority has been given in Paper No. _____ to charge/credit DEPOSIT ACCOUNT No. _____ for following:	<input type="checkbox"/> All Fees
		<input type="checkbox"/> 1.16 Fees (Filing) <input type="checkbox"/> 1.17 Fees (Processing Ext. of time) <input type="checkbox"/> 1.18 Fees (Issue) <input type="checkbox"/> Other _____ <input type="checkbox"/> Credit